

K-no.: 24620

100 A Current Sensor Module for 5V- Supply Voltage

Date: 14.07.2014

For electronic current measurement:
DC, AC, pulsed, mixed ..., with a galvanic
isolation between primary circuit
(short power) and secondary circuit
(electronic circuit)

Customer: Standard type

Customers Part no.:

Page 1 of 2

Description

- Closed loop (compensation)
Current Sensor with magnetic
field probe
- Printed circuit board mounting
- Casing and materials UL-listed

Characteristics

- Excellent accuracy
- Very low offset current
- Very low temperature dependency and offset
current drift
- Very low hysteresis of offset current
- Short response time
- Wide frequency bandwidth
- Compact design
- Reduced offset ripple

Applications

Mainly used for stationary operation in industrial
applications:

- AC variable speed drives and servo motor
drives
- Static converters for DC motor drives
- Battery supplied applications
- Switched Mode Power Supplies (SMPS)
- Power Supplies for welding applications
- Uninterruptible Power Supplies (UPS)

Electrical data – Ratings

I_{PN}	Primary nominal r.m.s. current	100	A
V_{out}	Output voltage @ I_P	$V_{Ref} \pm (0.625 \cdot I_P / I_{PN})$	V
V_{out}	Output voltage @ $I_P=0$, $T_A=25^\circ\text{C}$	$V_{Ref} \pm 0.0025$	V
V_{Ref}	External Reference voltage range	0...4	V
	Internal Reference voltage	2.5 ± 0.005	V
K_N	Turns ratio	1...3 : 1100	

Accuracy – Dynamic performance data

		min.	typ.	max.	Unit
$I_{P,max}$	Max. measuring range	±200			
X	Accuracy @ I_{PN} , $T_A=25^\circ\text{C}$			0.7	%
ε_L	Linearity			0.1	%
$V_{out} - V_{Ref}$	Offset voltage @ $I_P=0$, $T_A=25^\circ\text{C}$			±2.5	mV
$\Delta V_o / V_{Ref} / \Delta V$	Temperature drift of V_{out} @ $I_P=0$, $T_A=-40...85^\circ\text{C}$		3	10	ppm/°C
t_r	Response time @ 90% von I_{PN}		500		ns
$\Delta t (I_{P,max})$	Delay time at $di/dt = 100 \text{ A}/\mu\text{s}$		500		ns
f	Frequency bandwidth	DC...100			kHz

General data

		min.	typ.	max.	Unit
T_A	Ambient operating temperature	-40		+85	°C
T_S	Ambient storage temperature	-40		+85	°C
m	Mass		15		g
V_C	Supply voltage	4.75	5	5.25	V
I_C	Current consumption		16		mA
	Constructed and manufactured and tested in accordance with EN 61800-5-1 (Pin 1 - 6 to Pin 7 – 10) Reinforced insulation, Insulation material group 1, Pollution degree 2				
S_{clear}	Clearance (component without solder pad)	10.2			mm
S_{creep}	Creepage (component without solder pad)	10.2			mm
V_{sys}	System voltage			600	V_{RMS}
V_{work}	Working voltage				
	overvoltage category 3				
	(table 7 acc. to EN61800-5-1)				
	overvoltage category 2			1020	V_{RMS}
U_{PD}	Rated discharge voltage			1400	V_P
	Max. potential difference acc. to UL 508		RMS	600	V_{AC}

Date	Name	Issue	Amendment
14.07.14	DJ	84	Sensor optimised. Marking updated. CN-981
25.04.13	KRe	83	Mechanical outline: marking with UL-sign and max potential difference added. CN-666

Hrsg.: KB-E editor	Bearb.: Le designer	KB-PM: Ga. check	freig.: HS released
-----------------------	------------------------	---------------------	------------------------

K-no.: 24620

100 A Current Sensor Module for 5V- Supply Voltage

For electronic current measurement:
DC, AC, pulsed, mixed ..., with a galvanic
isolation between primary circuit
(short power) and secondary circuit
(electronic circuit)

Date: 14.07.2014

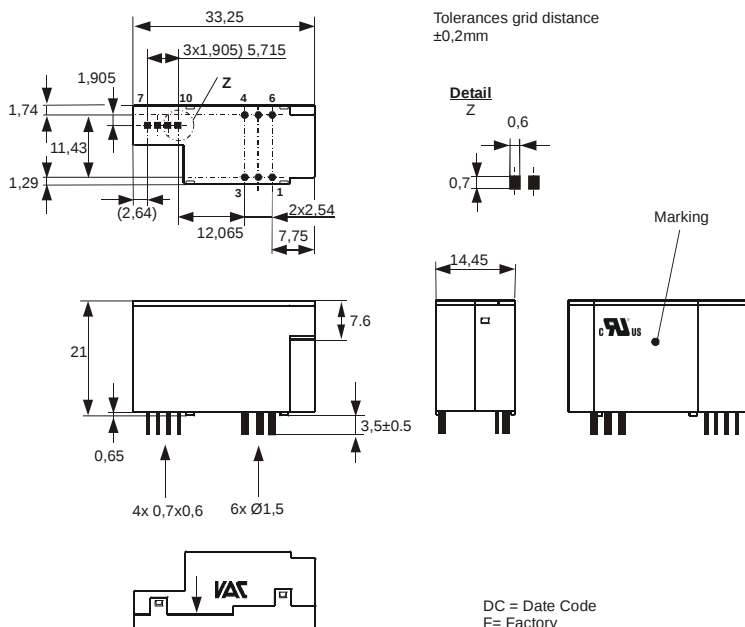
Customer: Standard type

Customers Part no.:

Page 2 of 2

Mechanical outline (mm):

General tolerances DIN ISO 2768-c



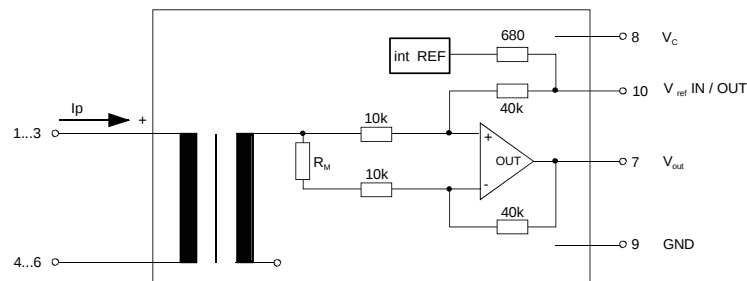
Connections:

1...6: Ø 1.5 mm
7...10: 0.7*0.6 mm

Marking:

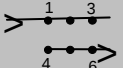
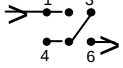
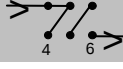
UL-sign
4646-X461
F DC

Schematic diagram



Possibilities of wiring

(@ T_A = 85°C)

primary windings	primary current RMS	primary current maximal	output current RMS	turns ratio	primary resistance	wiring
N _P	I _P [A]	I _{P,max} [A]	I _S (I _P) [mA]	K _N	R _P [mΩ]	
1	100	±200	2.5±0.625	1:1100	0.1	
2	50	±100	2.5±0.625	2:1100	0.45	
3	33.3	±66	2.5±0.625	3:1100	1	

Temperature of the primary conductor should not exceed 100°C.

Additional information is obtainable on request.

This specification is no declaration of warranty acc. BGB §443.

Hrsg.: KB-E
editor

Bearb.: Le
designer

KB-PM: Ga.
check

freig.: HS
released

K-No.: 24620

100 A Current Sensor Module for 5V- Supply Voltage

For the electronic measurement of currents:

DC, AC, pulsed, mixed ..., with a galvanic

Isolation between the primary circuit

(high power) and the secondary circuit

Date: 14.07.2014

Customer:

Customers Part No.:

Page 1 of 2

Electrical Data

		min.	typ.	max.	Unit
V_{Ctot}	Maximum supply voltage (without function)			6	V
I_C	Supply Current with primary current		$16mA + I_P \cdot K_N + V_{out}/R_L$		mA
$I_{out,SC}$	Short circuit output current		± 20		mA
R_P	Resistance / primary winding @ $T_A=25^\circ C$			0.3	m Ω
R_S	Secondary coil resistance @ $T_A=85^\circ C$			15	Ω
$R_{i,Ref}$	Internal resistance of Reference input		670		Ω
$R_{i,(V_{out})}$	Output resistance of V_{out}			1	Ω
R_L	External recommended resistance of V_{out}	1			k Ω
C_L	External recommended capacitance of V_{out}			500	pF
$\Delta X_{Ti} / \Delta V$	Temperature drift of X @ $T_A = -40 \dots +85^\circ C$			40	ppm/K
$\Delta V_0 = \Delta(V_{out} - V_{Ref})$	Sum of any offset drift including:		2	6	mV
V_{0t}	Longterm drift of V_0		1		mV
V_{0T}	Temperature drift von V_0 @ $T_A = -40 \dots +85^\circ C$		1		mV
V_{0H}	Hystereses of V_{out} @ $I_P=0A$ (after an overload of $10 \times I_{PN}$)			0.5	mV
$\Delta V_0 / \Delta V_C$	Supply voltage rejection ratio			1	mV/V
V_{OSS}	Offsettriple (with 1 MHz- filter first order)			21	mV
V_{OSS}	Offsettriple (with 100 kHz- filter first order)		3.5	6	mV
V_{OSS}	Offsettriple (with 20 kHz- filter first order)		1	1.5	mV
C_k	Maximum possible coupling capacity (primary – secondary)		5		pF
	Mechanical stress according to M3209/3			30g	
	Settings: 10 – 2000 Hz, 1 min/Oktave, 2 hours				

Inspection (Measurement after temperature balance of the samples at room temperature, SC = significant characteristic)

$V_{out}(SC)$	(V)	M3011/6:	Output voltage vs. reference ($I_P=3 \times 10A_{Peak}$, 40-80Hz)	$625 \pm 0,7\%$	mV
$V_{out}-V_{Ref}$	(V)	M3226:	Offset voltage ($I_P=0A$)	± 0.0025	V
V_d	(V)	M3014:	Test voltage, 1 s pin 1 – 6 vs. pin 7 – 10	2.5	kV _{RMS}
V_e	(AQL 1/S4)		Partial discharge voltage acc.M3024 with V_{vor}	1500 1875	V _{RMS} V _{RMS}

Type Testing (Pin 1 - 6 to Pin 7 – 10)

V_W			HV transient test according to M3064 (1,2 μs / 50 μs -wave form)	8	kV
V_d			Testing voltage to M3014 (5 s)	5	kV
V_e			Partial discharge voltage acc.M3024 with V_{vor}	1500 1875	V _{RMS} V _{RMS}

Applicable documents

Current direction: A positive output current appears at point V_{out} , by primary current in direction of the arrow.

Further standards UL 508 ; file E317483, category NMTR2 / NMTR8

Enclosures according to IEC529: IP50.

Date	Name	Issze	Amendment				
14.07.14	DJ	84	Sensor optimised. CN-998				
25.04.13	KRe	83	Applicable documents: further standards added. CN-666				
Hrsg.: KB-E editor	Bearb.: DJ designer		KB-PM: Ga. check				freig.: HS released

Weitergabe sowie Vervielfältigung dieser Unterlage, Verwertung und Mitteilung ihres Inhalts nicht gestattet, soweit nicht ausdrücklich zugestanden. Zuwiderhandlungen verpflichten zu Schadenersatz. Alle Rechte für den Fall der Patenterteilung oder GM-Eintragung vorbehalten

Copying of this document, disclosing it to third parties or using the contents there for any purposes without express written authorization by use illegally forbidden.
Any offenders are liable to pay all relevant damages.

K-No.: 24620

100 A Current Sensor Module for 5V- Supply Voltage

For the electronic measurement of currents:

DC, AC, pulsed, mixed ..., with a galvanic

Isolation between the primary circuit
(high power) and the secondary circuit

Date: 14.07.2014

Customer:

Customers Part No.:

Page 2 of 2

Explanation of several of the terms used in the tablets (in alphabetical order)

t_r : Response time (describe the dynamic performance for the specified measurement range), measured as delay time at $I_P = 0,9 \cdot I_{PN}$ between a rectangular current and the output voltage $V_{out}(I_P)$

$\Delta t(I_{Pmax})$: Delay time (describe the dynamic performance for the rapid current pulse rate e.g short circuit current) measured between I_{Pmax} and the output voltage $V_{out}(I_{Pmax})$ with a primary current rise of $di_P/dt \geq 100 \text{ A}/\mu\text{s}$.

U_{PD} Rated discharge voltage (recurring peak voltage separated by the insulation) proved with a sinusoidal voltage V_e
 $U_{PD} = \sqrt{2} \cdot V_e / 1,5$

V_{vor} Defined voltage is the RMS value of a sinusoidal voltage with peak value of $1,875 \cdot U_{PD}$ required for partial discharge test in IEC 61800-5-1

$$V_{vor} = 1,875 \cdot U_{PD} / \sqrt{2}$$

V_{sys} System voltage RMS value of rated voltage according to IEC 61800-5-1

V_{work} Working voltage voltage according to IEC 61800-5-1 which occurs by design in a circuit or across insulation

V_o : Offset voltage between V_{out} and the rated reference voltage of $V_{ref} = 2,5V$.

$$V_o = V_{out}(0) - 2,5V$$

V_{OH} : Zero variation of V_o after overloading with a DC of tenfold the rated value

V_{Ot} : Long term drift of V_o after 100 temperature cycles in the range -40 bis 85 °C.

X : Permissible measurement error in the final inspection at RT, defined by

$$X = 100 \cdot \left| \frac{V_{out}(I_{PN}) - V_{out}(0)}{0,625V} - 1 \right| \%$$

$X_{ges}(I_{PN})$: Permissible measurement error including any drifts over the temperature range by the current measurement I_{PN}

$$X_{ges} = 100 \cdot \left| \frac{V_{out}(I_{PN}) - 2,5V}{0,625V} - 1 \right| \% \quad \text{or} \quad X_{ges} = 100 \cdot \left| \frac{V_{out}(I_{PN}) - V_{ref}}{0,625V} - 1 \right| \%$$

ε_L : Linearity fault defined by $\varepsilon_L = 100 \cdot \left| \frac{I_P}{I_{PN}} - \frac{V_{out}(I_P) - V_{out}(0)}{V_{out}(I_{PN}) - V_{out}(0)} \right| \%$

This "Additional information" is no declaration of warranty according BGB §443.

Hrsg.: KB-E
editor

Bearb.: DJ
designer

KB-PM: Ga.
check

freig.: HS
released